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Enhancing superconductivity of $Lu_5Rh_6Sn_{18}$ by atomic disorder

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For a number of skutterudite-related cage compounds, such as cubic $R_3M_4\mathrm{Sn}_{13}$ ($R = \mathrm{Ca}$ or La, $M = \mathrm{transition} d$ -electron metal) or tetragonal Y₅Rh₆Sn₁₈, we have previously reported the impact of various atomic defects in the crystal lattices on the normal-state and superconducting properties of these clathrates. In these quasi-skutterudites the nanoscale disorder and/or local inhomogeneity in composition lead to an abnormal increase in the superconductors $\mathrm{Lu}_{5-\delta}\mathrm{Rh}_6\mathrm{Sn}_{18}$ (tetragonal symmetry I4₁/acd). We have documented that Lu₅Rh₆Sn₁₈ does not crystallize in the assumed stoichiometry, but forms a 5-6-18 phase with a Lu-deficiency ($\delta \approx 0.5$). Our comprehensive investigations of electronic structure and thermodynamic and electrical transport properties documented a T_c increase in the more disordered sample (Sample 1). The quality of two investigated samples (Sample 1 and Sample 2) with similar stoichiometry, but different local inhomogeneity was obtained by microanalysis and electron transmission microscopy observations. The band structure calculations show a hybridization pseudogap in the electronic bands of stoichiometric Lu₅Rh₆Sn₁₈ at about 0.3 eV in respect to the Fermi level, ϵ_F . The *ab initio* calculations predict the scenario, that vacancies could shift this pseudogap towards ϵ_F , which is manifested by the Mott variable-range hopping behavior in the resistivity $\rho \sim T^{-1/4}$ of more homogeneous Sample 2.

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I. INTRODUCTION

The effect of disorder on superconductivity has been investigated on a variety of diverse superconducting materials for many decades. The earliest understanding of this phenomenon was due to Anderson's theorem¹ which predicts that the conventional BCS superconductors with isotropic superconducting s-wave gap generally are not sensitive to dilute nonmagnetic impurities. while even small presence of magnetic dopants can drastically reduce the critical temperature of their superconducting state $^{2-4}$. In the case of a strongly anisotropic gap, T_c should also be reduced by nonmagnetic impurities. Several theoretical calculations of T_c suppression have also discussed the pair-breaking effects of nonmagnetic scatterers on model multiband superconductors with generalized s-wave order⁵. This topic has received renewed attention because of the several new reports of the observation of novel phenomena in a number of strongly disordered superconductors, especially at the limit of critical disorder leading to complete destruction of superconductivity^{6,7}. In most investigated superconductors the disorder is associated with presence of atomic scale disorder generated by impurities, structural defects or local inhomogeneity, and leads to electronic inhomogeneity over the length scales of the coherence length ξ . Therefore, unexpected observations of an enhancement of the superconducting transition temperature, T_c , when the amount of disorder in a material is increased, are particularly interesting and have received our attention. In particular, the investigations of novel strongly correlated superconductors $(SCS)^{8-10}$ have shown that the atomic disorder, acting as a perturbation within the critical regime, can be decisive and changes the nature of the quantum macrostate either in the normal and superconducting phase. The disorder as perturbation can lead to novel phenomena like the disorder-enhanced superconductivity, discovered in a series of $SCSs^{10-16}$ and high-T_c $Bi_2Sr_2CaCu_2O_{8+x}$ -type materials¹⁷, however, the mechanism of T_c increasing is still under the debate. Our present studies focus on the family of nonmagnetic skutterudite-related $R_3M_4Sn_{13}$ type superconductors (R = La, Y, or Ca, and M = delectron-type metal) with the atomic scale disorder causing appearance of novel high-temperature superconducting state with the critical temperature $T_c^{\star} > T_c^{15}$. Several experimental and theoretical attempts have been undertaken to answer the question: why the supercon-

undertaken to answer the question: why the superconductivity, characterized by the critical temperature T_c , is enhanced when the amount of disorder increases (e.g., Refs.^{18,19}). Gastiasoro and Andersen¹⁸ theoretically explained disorder-generated T_c increase for two separate scenarios: dilute disorder case in multiband superconductors, and dense disorder in conventional one-band superconducting systems. The proposed mechanisms model well enough the superconductivity of the disordered quasi-skutterudites both at the small and large limit of disorder¹⁹. The current investigations of the series of $\text{Lu}_{5-\delta}\text{Rh}_6\text{Sn}_{18}$ quasi-skutterudite compounds enable us to verify the validity of Gastiasoro and Andersen theoretical predictions for systems with low concentration of defects and those having strong fluctuation in homogeneity, as well as to predict experimentally the impact of the disorder strength on enhancement of the superconducting state.

II. EXPERIMENTAL AND COMPUTATIONAL DETAILS

The "Lu₅Rh₆Sn₁₈" (Sample 1) and "Lu_{4.6}Rh₆Sn₁₈" (Sample 2) polycrystalline samples were prepared by arc melting technique and then annealed at 870° C for 2 weeks. All samples were examined by x-ray diffraction (XRD) analysis and found to have a tetragonal structure (space group $I4_1/acd$)^{20,21}. Parametric XRD studies were carried out at the X-ray Science Division beamline 17BM²² at the Advanced Photon Source, Argonne National Laboratory (Argonne, USA) with an incident X-ray energy of approximately 51 keV (wavelength $\lambda = 0.24177$ Å). Series of diffractograms were collected on a heat up ramp from 100 K to 500 K (360 K/h) using an area detector and processed using GSAS-II software package²³. Structural serial refinements were carried out using FULLPROF software suite²⁴. Temperature dependence of the cell volume was modeled using a second order Debye-Grüneisen fit described by Wood *et al.*²⁵. The samples were labeled on the basis of the SEM study as $Lu_5Rh_6Sn_{18}$ (sample 1) and $Lu_{4,6}Rh_6Sn_{18}$ (sample 2), respectively. The naming scheme was preserved in the plots. Stoichiometry and homogeneity were checked by electron microprobe technique [scanning electron microscope JSM-5410 equipped with an energy-dispersive Xray spectrometry (EDXS) microanalysis system]. The transmission electron microscopy (TEM) observations of the surface images and structural properties of nm size crystallites were performed using a JEOL high resolution (HRTEM) JEM 3010 microscope operating at a 300 kV accelerating voltage and equipped with a Gatan $2k \times 2k$ OriusTM 833SC200D CCD camera.

Electrical resistivity ρ was investigated by a conventional four-point ac technique using a PPMS (physical properties measurement system) device. Similarly, the PPMS platform was used to measure magnetic ac susceptibility. The dc magnetic susceptibility and magnetization measurements were carried out in the temperature range 1.8 - 400 K and in applied magnetic fields up to 7 T using a Quantum Design superconducting quantum interference device (SQUID) magnetometer.

The XPS spectra were obtained at room temperature in the vacuum of 8×10^{-8} Pa (6×10^{-10} Torr) using a PHI 5700 ESCA spectrometer with monochromatized Al K_{α} radiation. The samples were broken under a high vacuum before measuring the spectra.

The electronic band structure of stoichiometric $Lu_5Rh_6Sn_{18}$ was calculated using the full-potential linearised augmented plane waves (FP-LAPW) method complemented with local orbitals $(LO)^{26}$ implemented in the WIEN2k computer $code^{27}$. The *ab initio* calculations were performed for the paramagnetic compound with the formula $Lu_{5-\delta}Rh_6Sn_{18}$, using the experimental lattice parameters (tetragonal structure, space group $I4_1/acd$ (for details on similarly made computations see. e.g., in^{28}) In the performed calculations we assumed the set of local orbitals (LO) and valence states (VB), respectively as follow: Lu - $[5s^25p^6]_{\text{LO}}\{4f^{14}5d^16s^2\}_{\text{VB}};$ Rh - $[4s^24p^6]_{\text{LO}}\{4d^85s^1\}_{\text{VB}};$ Sn - $[4p^64d^{10}]_{\text{LO}}\{5s^25p^2\}_{\text{VB}}),$ and the scalar-relativistic Kohn-Sham was applied with spin-orbit coupling (SOC) accounted for by means of second variational method²⁶. The gradient approximation form (GGA) of the exchange-correlation energy functional together with parametrization (PBEsol) derived for solids by Perdew $at al.^{29}$ were applied. The k-mesh was tested against the total energy convergence and satisfactory precision, of few meV, was achieved with $7 \times 7 \times 7$ mesh $(N_k = 40\vec{k} \text{ vectors in irreducible Brillouine zone})$ (IBZ)).

III. RESULTS AND DISCUSSION

A. $\operatorname{Lu}_{5-\delta}\operatorname{Rh}_6\operatorname{Sn}_{18}$; microanalysis and structural properties

Our intention was to obtain the stoichiometric $Lu_5Rh_6Sn_{18}$ (labelled as Sample 1) and off-stoichiometric $Lu_{4.6}Rh_6Sn_{18}$ (Sample 2) compounds. It turns out, however, that system 5-6-18 does not crystallize in the assumed stoichiometry, but forms a 5-6-18 phase with a Ludeficiency, and the obtained, arc melted, $Lu_{5-\delta}Rh_6Sn_{18}$ compositions differ from the initially assumed stoichiometry (for the both samples $\delta \approx 0.5$). The energy dispersive X-ray analysis gives the average Lu:Rh:Sn stoichiometric ratio for the sample surface, respectively $4.55 \pm 0.25 : 6.0 \pm 0.23 : 17.75 \pm 0.30$ for Sample 1, and $4.49 \pm 0.20 : 6.0 \pm 0.18 : 17.90 \pm 0.22$ for Sample 2. Uncertainties are defined in acknowledgments. For simplicity, the correct formulas of $Lu_{5-\delta}Rh_6Sn_{18}$ -type compounds are replaced here by the expressions Sample 1 and Sample 2, respectively. EDXS indicates a similar atomic composition for Sample 1 (initially assumed as $Lu_5Rh_6Sn_{18}$) and its Lu-deficient Sample 2 variant. However, please note that the EDX picks up the signal from all phases present in the material and the Sample 1 will be shown to contain a tin-like impurity. In this sense, this is a phase content weighted average and might also include non-crystalline precipitations which are not picked up by the XRD. In Sample 2, we do not see a clean signal from tin so it will be closer to the one phase system. This observation shows that the thermodynamic equilibrium in the Lu-rich melt is achieved by separation of tin and that a single phase system is achieved in a Lu deficient melt.

A detailed structural characterization of the material is well beyond the size of this paper. The original paper of Hodeau et al.²¹ on (Sn,Eu)-Rh-Sn single crystals serves, as a good example for a complexity of such a task. The recent paper on a single crystal of " $Lu_5Rh_6Sn_{18}$ " ³⁰ (which was released after our submission) indicated that the Lu vacancy is filled by Sn. We have to note that the growth of a single crystal might have different thermodynamic equilibrium than arc-melting and annealing of powder. Therefore, it does not have to give the same atomic distribution as in our case. However, all studies show that the system is close to one phase equilibrium with a preference for deficiency of atoms in the Lu sites. Our recent TEM study on (Y,Ca)-Rh-Sn system¹⁹ has shown that even two separate but related structures like 3-4-13 $(Ca_3Rh_4Sn_{13})$ and 5-6-18 $(Y,Ca)_5Rh_6Sn_{18}$ can smoothly blend into each other within a few layers in one grain. We note that the 3-4-13 type cubic phase was not detected in this study, however, there are multiple structures related to the prototypical 3-4-13 system, for examples see^{31} . Local fluctuations in stoichiometry over the length of the sample were observed at the nanoscale both in samples 1 and 2 due to intersite atomic disorder and/or atom displacements³², as shown in Fig. 1. The stronger fluctuations in both atomic disorder and composition of larger volume fractions of $\sim 20 \ \mu m$ are observed for Sample 1, as panel (a) shows, while the effect is not visible for sample 2. We have recently shown¹⁹ that similar fluctuations in concentration over larger areas of a sample volume of the isostructural compound $Y_5Rh_6Sn_{18}$ can significantly increase its superconducting temperature T_c , especially when the elemental local atomic disorder is strongly enhanced by doping. Likewise, we have expected that the local distortion in stoichiometry would also be the reason for a similar increase in T_c for Sample 1. Indeed, within the investigated series of the $Lu_{5-\delta}Rh_6Sn_{18}$ compounds $(\delta \approx 0.5)$, the superconducting transition temperature $T_c=4.09~{\rm K}$ of sample 1 is evidently larger than $T_c=3.69$ K of sample 2, for which the composition is more stable within the volume of the sample.

The structural studies revealed that Sample 1 had a multiphase character with a minority phase initially identified as a tetragonal tin and another unidentified weak contribution. The tin-like impurity was not present in Sample 2. The multiphase character of Sample 1 indicates that its stoichiometry obtained by SEM is a sum of contributions from all of the phases present in the material. This problem was addressed in the XRD analysis, since it allows to estimate the composition of each crystallographic phase separately. The structural models proposed here are based on the results of similar structural investigations for isostructural 5-6-18 crystals, previously reported by Hodeau *et al.*²¹ and our group²⁸, and the notation for the formula unit was kept accordingly.

The large size of the tetragonal unit cell makes it impossible to uniquely refine all structural parameters even from a single crystal measurement. Therefore in this study, a simplified model based on our previous approach^{19,28} was 3



FIG. 1. Variation in stoichiometry of Sample 1 (panel a) and Sample 2 (panel b) over the length of the sample. The yellow curve in panel (a) is rough approximation of the fluctuating Sn around mean content of 17.9 by $\Lambda sin(\frac{2\pi}{\Delta l}l)$ function with amplitude $\Lambda = 1.6$ and $\Delta l = 23 \ \mu m$, where Δl could express a diameter of the extent of strong fluctuations in composition. $\Lambda sin(\frac{2\pi}{\Lambda l})$ function enough well fits the experimental data in the region up to about 800 μ m, although the fluctuations in composition are observed for higher values of l too.

used. There were four main issues to be addressed during the refinement: (i) a mixed and possibly less than 1 occupancy of Lu1/Sn1 site, (ii) an incomplete occupancy of Lu2 site, (*iii*) fractional filling of the following Sn sites: Sn2, Sn31, Sn32, Sn33, Sn34 and Sn4, (iv) large positional disorder vs "rattling" of the Sn4 site. Our previous results documented that the atomic displacement parameters (ADP) of the framework (Lu, Rh, Sn other than Sn4) are similar to each other ($\approx 1 \text{ Å}^2$), but differ significantly from the behavior of the Sn4 site $(> 3 \text{ Å}^2)$, i.e., in the cage frame for the Sn4 site, its APD was at least 5 times larger than for the rest of atoms. Therefore only two ADPs were used: the first one for the *rattling* Sn4 and the second one for all other atoms. Chemical occupancy of the sites was evaluated by refining different models from two datasets collected at 100 K and 500 K. No significant departures from a full occupancy were observed. Then, for the serial refinements, the number of parameters was further reduced by assigning full occupancy to all sites except the Lu1/Sn1 one, which might be prone to fractional occupancy²¹. The diffraction results confirm that fractional occupancy is not affected by the temperature. The XRD study allowed us to obtain structural information about the materials. For Sample 1 an additional phase was identified as tetragonal tin with the mass fraction estimated to be 8.1(2)%. This phase was included in the refinement. We note, however, that a structural gray-tin-white-tin transition has not been observed down to 100 K, which means that the secondary phase is most probably the tin alloy³³. An example of a complete set of patterns for Sample 1 is presented in Fig. 2. The data presented in Table II were refined



FIG. 2. Low angle section of the merged diffractograms for Sample 1. Intensity is presented on a logarithmic scale to magnify weak peaks.

assuming first a full Lu1/Sn1 site occupancy with a refineable mixing factor. This approach was successful in the case of Sample 1 (the first two columns) but resulted in negative Lu fraction for Sample 2 (the data are not presented in the table). Such behavior was indicative of a non full Lu1 site occupancy as was observed earlier by Hodeau *et al.* for $(Sn_{1-x}Er_x)Er_4Rh_6Sn_{18}$ ²¹ and our group for $(\operatorname{Sn}_{1-x}\operatorname{Y}_x)\operatorname{Y}_4\operatorname{Rh}_6\operatorname{Sn}_{18}^{28}$. Despite this earlier observation we have tried to refine it anyhow, since the excess of tin in Sample 1 suggested such possibility. The final round of the refinements were performed for a fractional and only by Lu occupied the Lu1 sites (columns 3 - 6), in a way similar to previous studies. Modeling with the change of the Lu1 site occupation did not affect other structural parameters, which for the same conditions remained similar within a fitting error (columns 1 and 3, 2 and 4). The results indicate that both samples were affected by an off-stoichiometry obtained with large statistical uncertainties. This issue was encountered earlier in our previous studies of similar materials. A relative error of the occupancy of each tin site is less than 2.5%,



FIG. 3. Plots of Rietveld refinement for Sample 2 (top) and Sample 1 (bottom). Black dots - observed pattern, red line - calculated, blue ticks - Bragg peak positions, magenta line - the difference. Insets in each plot show magnified regions from the end of the patterns. On the bottom plot, the second set of blue markers indicates positions of tin impurity, which is enhanced in the inset "Sn" in the bottom panel. The two strongest reflections visible in the bottom panel from the tinlike phase in Sample 1 (red line) are (200) at 4.75 deg and (101) at 4.97 deg respectively. They are not present in Sample 2 (blue line).

but the number of Sn sites (up to 7) multiplies it to a significant value. Therefore, despite the fact that XRD does allow to decouple compositions of each phase, the comparison and discussion with the SEM results from a large sample area is impossible.

Comparison of the 100 K and 500 K datasets justifies the absence of significant relative atom movements within the cell. However, following our structural investigations of the inhomogeneity found in the system of $Y_{5-x}Ca_xRh_6Sn_{18}$ compounds, where two related structures of 3-4-13 and 5-6-18-type smoothly blend into each other within one grain¹⁹, we have searched for a similar subtle phase changes in $Lu_{5-\delta}Rh_6Sn_{18}$. For this purpose, the full temperature range was fit using a second order Debye-Grüneisen model for the cell expansion with parametrization suggested by Wood *et al.*²⁵. The results of this approach for both 5-6-18 phases and the tin impurity are presented in Fig. 4 and in Table I. The fitting gave very good results in the case of Sample 1 and the tin-like impurity. For Sn-rich impurity phase the obtained De-

TABLE I. Parameters obtained from a Grüneisen model of cell expansion²⁵. N_{at} - number of atoms in the unit cell, θ_D - Debye temperature, V_0 - cell volume at 0 K, $b = (K'_0 - 1)/2$, $Q = V_0 K_0/\gamma_G$, where K_0 and K'_0 are the incompressibility and its first derivative vs pressure, γ_G is a Grüneisen parameter. (*) Parameter b for Sample 1 has possibly a nonphysical value which is connected with a non-Debye expansion (see Fig. 5)

Sample	N_{at}	θ_D (K)	V_0 (Å ³)	b~(-)	Q (eV)
Sample 1	232	407(4)	5129.07(8)	-7.7(3)(*)	1466(7)
Sample 2	232	348(8)	5138.87(7)	3.7(3)	1921(9)
Sn	4	246(7)	107.722(6)	7.6(2)	18.8(2)

TABLE II. Parameters of Sample 1 and Sample 2 superconductors obtained from the structural study. Space group I4₁/acd. For details of notation please check Ślebarski *et al.*²⁸. $R_p/R_{wp}/R_{exp}$ - conventional, background corrected, Rietveld factors. XRD composition is normalized to Rh₆, which for brevity is replaced with a (=).

Sample	Sample 1 (100 K)	Sample 1 (500 K)	Sample 1 (100 K)	Sample 1 (500 K)	Sample 2 (100 K)	Sample 2 (500 K)
Model	${ m Sn1/Lu1}$ full	${ m Sn1/Lu1}$ full	Lu1 fract.	Lu1 fract.	Lu1 fract.	Lu1 fract.
XRD compos.	$Lu_{3.7(3)}(=)Sn_{17(1)}$	$Lu_{3.7(2)}(=)Sn_{17(1)}$	$Lu_{4.1(2)}(=)Sn_{17(1)}$	$Lu_{4.1(2)}(=)Sn_{17(1)}$	$Lu_{4.1(1)}(=)Sn_{16.9(8)}$	$Lu_{4.2(1)}(=)Sn_{16.5(8)}$
a (Å)	13.7012(2)	13.7590(2)	13.7012(2)	13.7590(2)	13.7069(2)	13.7636(2)
c (Å)	27.3462(7)	27.4744(8)	27.3465(7)	27.4747(8)	27.3735(5)	27.4837(6)
V (Å ³)	5133.5(2)	5201.2(2)	5133.6(2)	5201.2(2)	5142.9(1)	5206.4(2)
B_{iso} other (Å ²)	0.48(4)	1.39(4)	0.51(4)	1.42(4)	0.44(3)	1.17(3)
B_{iso} Sn4 (Å ²)	5.9(4)	7.0(3)	5.7(4)	6.9(3)	3.1(2)	4.0(2)
SOF Lu1/Sn1	0.40/0.60(2)	0.40/0.60(2)	0.796(4)/0	0.800(4)/0	0.580(4)/0	0.572(4)/0
\mathbf{Z}_{Rh1}	-0.0032(7)	-0.0034(8)	-0.0030(7)	-0.0032(8)	-0.0036(6)	-0.0034(6)
X_{Rh2}	0.2421(6)	0.2424(8)	0.2422(6)	0.2424(8)	0.2437(6)	0.2438(6)
y_{Rh2}	0.2486(5)	0.2490(5)	0.2487(5)	0.2491(5)	0.2504(4)	0.2502(4)
\mathbf{Z}_{Rh2}	-0.125(2)	-0.125(2)	-0.125(2)	-0.125(2)	-0.1249(7)	-0.1252(7)
X_{Lu2}	0.1327(5)	0.1320(5)	0.1327(5)	0.1320(5)	0.1328(3)	0.1319(4)
y_{Lu2}	0.3864(5)	0.3853(5)	0.3864(5)	0.3853(5)	0.3867(3)	0.3862(3)
\mathbf{Z}_{Lu2}	-0.1920(2)	-0.1920(2)	-0.1920(2)	-0.1920(2)	-0.1926(2)	-0.19220(2)
X_{Sn2}	0.0884(6)	0.0894(6)	0.0887(6)	0.0895(6)	0.0874(4)	0.0888(5)
y_{Sn2}	0.3380(6)	0.3394(5)	0.3380(6)	0.3394(6)	0.3385(4)	0.3393(4)
Z_{Sn2}	-0.0787(3)	-0.0782(3)	-0.0789(3)	-0.0783(3)	-0.0806(2)	-0.0806(2)
\mathbf{x}_{Sn31}	0.1811(5)	0.1786(6)	0.1815(6)	0.1790(6)	0.1746(6)	0.1727(5)
\mathbf{x}_{Sn32}	0.3193(6)	0.3216(7)	0.3188(6)	0.3212(7)	0.3276(6)	0.3291(5)
\mathbf{x}_{Sn33}	0.3300(10)	0.3289(11)	0.3301(10)	0.330(2)	0.3262(6)	0.3256(6)
y_{Sn33}	0.2619(5)	0.2615(5)	0.2619(5)	0.2613(5)	0.2622(4)	0.2620(4)
\mathbf{Z}_{Sn33}	-0.0383(6)	-0.0381(7)	-0.0384(6)	-0.0382(7)	-0.0389(3)	-0.0392(3)
\mathbf{x}_{Sn34}	0.0070(5)	0.0046(5)	0.0069(5)	0.0045(5)	0.0040(3)	0.0025(4)
y_{Sn34}	0.5773(10)	0.5769(12)	0.5778(10)	0.5775(12)	0.5710(8)	0.5687(7)
Z_{Sn34}	-0.0377(6)	-0.0378(8)	-0.0377(6)	-0.0378(8)	-0.0364(4)	-0.0358(4)
y_{Sn4}	0.4692(8)	0.4732(8)	0.4692(8)	0.4732(8)	0.4614(4)	0.4621(5)
$R_p/R_{wp}/R_{exp}$	10.9/12.8/3.01	11.0/12.0/3.46	11.0/12.8/3.01	11.0/12.1/3.46	7.43/9.64/3.22	8.32/10.4/3.51



FIG. 4. Temperature dependence of cell volumes for the refined phases (black circles) were fit with a second-order Grüneisen fit (red line). The error bars of the refined parameters are smaller than the circle size (0.19 Å³ for Lu phases and 0.007 Å³ for the tin like impurity). The left axis presents differences between the experiment and the fit (blue dots).

by temperature agrees well with the tabulated value 34 . For Sample 2 the obtained θ_D value is higher than that expected from other measurements. One notes, however, that the strong enhancement of the highest phonon frequency $\omega_D \sim 1/M^{1/2}$ is expected due to the presence of rhodium, which is lighter than tin. Additionally, this value of θ_D might be different from that obtained from the low temperature specific heat data, as different and much higher phonon modes might be available at high temperatures. The problem in determination of θ_D arises for Sample 1, for which we have obtained a negative value of parameter b that we obtained (b describes dependence of incompressibility on pressure, see Table I). This behavior most likely indicates a phase transition (or an additional effect) disturbing the fit. In order to inspect this fact without imposing any physical model, we followed a procedure applied earlier ²⁸, which was based on a simple linear fit to volume change V(T) in the temperature



FIG. 5. Differences in the unit cell volume expansion visualized by a simple linear fit from 150 K to 400 K reveal similar behavior for sample 2 (blue) and the tin-like impurity (green). Sample 1 (brown) displays a trend similar to $Y_5 Rh_6 Sn_{18}^{28}$ which is included as an inset in the right bottom corner. Sample 1 might not follow a Grüneisen-like evolution. Error bars represent 1- σ confidence level.

region between 150 K and 450 K, with accompanying T-anomalies in resistivity and specific heat (see Section III.C.). The differences $\Delta V = V - (aT + b)$ for all materials are presented in Fig. 5. The change $\Delta V(T)$ is similar for Sample 2 and impurity Sn-based phase, while it looks different for Sample 1. This behavior could only suggest a possible phase transition in Sample 1, however, this behavior is not an unequivocal confirmation of the structural transition. The $\Delta V(T)$ looks similar to the one presented for the Y₅Rh₆Sn₁₈²⁸ (Fig. 13 therein).

B. Band structure of $Lu_5Rh_6Sn_{18}$, electrical resistivity and thermodynamic characterization

The *ab initio* calculations documented that the correlation energy U significantly modifies the calculated Lu 4felectronic states of stoichiometric Lu₅Rh₆Sn₁₈ within the range of binding energies (-12 < E < -6) eV, while its impact on the shape of the total density of states (TDOS) located between -6 eV and the Fermi energy is negligible. For DFT calculations we have chose $U_f=(3, 4.5, 5.5, \text{ and}$ 6.8) eV. For all calculations made for a number of different ($0 \le U_f \le 6.8$) eV, the *d*-electron correlations with $U_d = 3$ eV were always taken into account the same^{35,36}. Figure 6 compares the valence XPS spectra of Sample 1 and Sample 2 with the calculated TDOS for $U_f = 3$ eV (blue line) and 6.8 eV (brown line), respectively. The Lu 4f-electron XPS states are well accounted for by the Lu 4f states calculated for $U_f = 6.8$ eV, which suggests that the DFT calculations with $U_f = 6.8$ eV and accompanying $U_d = 3$ eV are the most reasonable for obtaining the details in the electronic bands near the Fermi level and the value of TDOS, $2N(\epsilon_F)$, at ϵ_F . Figure 7 shows the energy distribution of the summarized s, p, d, and f electronic states for all Lu, Rh and Sn atoms in the $Lu_5Rh_6Sn_{18}$ formula unit, located in the bands near the Fermi level. Thus, it is possible to precisely determine the contributions of various conduction electrons to the electrical transport of $Lu_5Rh_6Sn_{18}$, as well as explain the different $\rho(T)$ characteristics obtained for Sample 1 (a) and more off-stoichiometric Sample 2 (b).

The VB XPS spectra shown in Fig. 6 are dominated either by the Rh 4d and Sn 5p states near ϵ_F or by Lu 4f states located deeply between -6 eV and -11 eV in the valence XPS bands. For binding energies (-3 to -11) eV the Sn 5s-states also give a significant contribution to the intensity of the VB XPS spectra. We also studied the binding energy spectrum of individual atoms to provide information about the ionic state of atoms and thus the change in local structure and better information about disorder within the unit cell and disorder in composition. To make a comparison, we measured the XPS spectra of Sn, Rh and Lu metals. Figure 6 shows the VB XPS spectra for the reference metals, where all spectra displayed in the figure are normalized to the background intensity for Sample 1. The Sn 5p XPS states measured for metallic tin show two broad maxima at the binding energy of ~ 1.3 eV and ~ 7.3 eV, while both the maxima are not present in the VB XPS spectra for sample 1 and 2, because they are covered by the Rh 4d and Lu 4f states, respectively. Therefore the analysis of the relative energy shift of the Sn 5p states located in the VB XPS spectra shown in Fig. 6 in respect to Sn metal is impossible. The VB XPS spectrum for pure Rh metal shows two maxima, at 2.1 eV and 2.8 eV, addressed to the distribution of the 4d electron states. Both maxima are also observed in the VB XPS spectra of sample 1 and 2 at about 2.3 and 3.3 eV. We suggest that the charge redistribution, due to covalent bonding between Rh and Lu states³⁷, is the dominating effect on the atomic 4dlevel shift, very similar in both samples. Perhaps most interesting is the information about the ionic state of Lu atoms and thus the change in local structure, as shown in Fig. 6. For this purpose, the 4f spectra of metallic Lu were compared with the $4f^{5/2}$ and $4f^{7/2}$ states in VB XPS spectra of Lu₅Rh₆Sn₁₈ sample and its offstoichiometric variant. For Lu metal the maxima of $4f^{5/2}$ and $4f^{7/2}$ XPS lines are at binding energy of 7.3 eV and 8.7 eV, respectively. While these maxima are clearly detected in the related VB XPS bands of Sample 1 and Sample 2, they are shifted to higher binding energies 7.7 eV and 9.1 eV, respectively. Again, from a similar atomic 4d-level shift one can speculate the formation of covalent bondings between Lu and neighboring atoms for both samples, however, one can not discuss strength of local disorder. However, the broader distribution of the 4f states documented for Sample 1 gives arguments for

stronger disorder, both compositional and within the unit cell, compared to Sample 2.

It is worth noting that at the binding energy around E = -0.3 eV there is a hybridization pseudogap in TDOS (see also Fig. 8), which can be shifted towards the Fermi level by the structural defects, as was documented by our previous ab initio calculations carried out for similar quasiskutterudites^{37,38}. It will be discussed below.

The bands of $Lu_5Rh_6Sn_{18}$ shown in Fig. 8 reveal the



FIG. 6. Valence band XPS spectra for Sample 1 (blue points) and Sample 2 (orange points) are compared with the calculated total DOS within the LSDA approximation. The blue curve shows the TDOS calculated for $U_f = 3$ eV and $U_d = 3$ eV, while the brown curve shows the calculated TDOS with $U_f = 6.8$ eV and $U_d = 3$ eV. The VB XPS spectra, measured for pure Lu, Rh, and Sn metals, are also shown. The intensities of all measured VB XPS bands are renormalized to the background for Sample 1 at $E > \epsilon_F$.

presence of (i) several Dirac cone-like shapes (e.g., on $\Gamma - Z - \Sigma 1$ symmetry lines) and (ii) the pseudogap with almost zero TDOS at ~ -0.3 eV. The first unusual behavior, (i), is characteristic of the special class of nonsymmorphic materials³⁹ with the presence of Dirac cones and Dirac nodes, while depending on the filling level of the bands, the non-symmorphic materials may also undergo Mott variable-range hopping $effect^{40,41}$ [the case (ii)] if the deep minimum in the *d*-electron DOSs would be located close to the Fermi level.

Figure 9 compares the ac mass susceptibility $\chi_{\rm ac}$ = $\chi' + \chi''$ of Sample 1 [panel (a)] and Sample 2 (b), measured at different frequencies with amplitude $2 \times 1000/4\pi$ A/m (2 Oe) of the applied ac field. The maxima in $d\chi'/dT$ and $d\chi''/dT$ define the critical temperature T_c and/or T_c^{\star} . The components χ' and χ'' shown in Fig. 9(b) indicate a broad transition between the normal and superconducting states in Sample 2, this signals that



FIG. 7. Sum of the s, p, and d electronic states in respective valence bands of Lu, Rh, and Sn in the Lu₅Rh₆Sn₁₈ formula unit, distributed near the Fermi level. All partial DOSs are calculated for $U_f = 6.8$ eV and $U_d = 3$ eV. In panel (b) total density of d-electron states calculated for four Rh atoms is multiplied by 1/10 to present all remaining atomic DOSs with the same scale.



FIG. 8. The band structure calculated along high symmetry k lines in the Brillouine zone (shown in the inset) of $Lu_5Rh_6Sn_{18}$ for $U_f = 6.8$ eV and accompanying $U_d = 3$ eV.

the inhomogeneous high temperature superconducting T_c^* phase is not well separated from the bulk superconducting one, giving $T_c^* \approx T_c$. In contrast to this behavior, the χ_{ac} data shown for Sample 1 in Fig. 9(a) signals the presence of an inhomogeneous superconducting T_c^* -phase well separated from the bulk T_c -phase, and both transitions are observed to be more narrow. One also notes



FIG. 9. Temperature dependencies of the real χ' and imaginary χ'' components of the ac mass magnetic susceptibility χ_{ac} per 1 Oe for Sample 1 [panel (a)] and Sample 2 (b), measured at different frequencies ν , and derivative $d\chi'/dT$ and $d\chi''/dT$ [the used unit $4\pi \times 10^{-3}$ m³/kg (SI) is equivalent to 1 emu/g (cgs)]. Panel (a) displays the data for inhomogeneous Sample 1, the first maximum in $d\chi'/dT$ is assigned to T_c^* of the inhomogeneous phase, the second weak maximum at ~ 3.85 K marked by an arrow is referred to the formation of the bulk T_c phase. Panel (b) shows a broad transition to the superconducting state of Sample 2 with very similar T_c and T_c^* .

the perfect diamagnetism of the full Meissner state with the expected value of $\chi' = -1/(4\pi d) \approx -8.5 \times 10^{-3}$ A m² kg⁻¹ (emu/g) and mass density d = 9.42 g/cm³ for both samples 1 and 2 at temperatures $T < T_c$ (c.f. Fig. 10)⁴². Figure 10 displays the magnetization M vs Bisotherms for Sample 1 [panel (a)] and Sample 2 [panel (b)]. The samples are diamagnetic with hysteresis loops in the superconducting state, representing the effect of vortex pinning. A very crude estimate gives the critical field $H_{c1} \approx 0.023$ T and ~ 0.006 T for sample 1 and



FIG. 10. The magnetization M isotherms vs magnetic field B for Sample 1 [panel (a)] and Sample 2 [panel (b)] at different temperatures [the used unit 1 A m²/kg (SI) is equivalent to 1 emu/g (cgs)]. (a) The left inset shows the hysteresis loop at T = 2 K for superconducting state of Sample 1, the lower inset exhibits the diamagnetic behavior at various temperatures T > 2 K. The inset in panel (b) exhibits the hysteresis loop measured for Sample 2 at T = 2.3 K.

2, respectively (230 and 60 G). The calculated critical fields H_{c1} are for sample 1 and 2 one order of magnitude smaller than those estimated experimentally (c.f. Table III), however, the relation between the respective calculated quantities $H_{c1}(a) > H_{c1}(b)$ matches the experimental data.

The magnetic data in Figs. 9 and 10 $(chi_{ac} \text{ and } M)$ show that samples 1 and 2 are diamagnetic in their normal state. The diamagnetic effect dominates the Pauli paramagnetism for $T > T_c$ and mostly results from Rh *d*-electron states (as results from DFT calculations) and Landau diamagnetism of the free electron gas (a Fermi surface effect). One can suppose that the electron states close to the Fermi surface are diamagnetically active, then, even a weak effect should be related to the DOS at ϵ_F . A comparison of the mass ac susceptibility in the normal state between these two compounds (see Fig. 9) gives $|\chi'_{ac}|$ of Sample 1 one order in magnitude larger than $|\chi'_{ac}|$ of Sample 2, which is evidence that the enhanced superconductivity in Lu_{5- δ}Rh₆Sn₁₈ is a result of the changed electronic structure at the Fermi level. The variation in DOS, depending on the sample stoichiometry, also significantly changes the temperature dependence of resistivity, as discussed below.

Figure 11 shows the specific heat of Sample 1 [panel (a)] and Sample 2 [panel (b)] at various magnetic fields (insets). As an attempt, the low-T C/T data at zero magnetic field have been approximated by a two-gap model. The two-gap scenario can be expected from the band structure calculations, which confirm the presence of various s, p, and d electronic states at the Fermi level, as Fig. 7 presents. Under the two-gap scenario the best fit is given by the expression:

$$\frac{C(T)}{T} = \gamma_0 ' + \beta ' T^2 + \frac{1}{T} A \left[y \exp\left(-\frac{\Delta_1}{k_{\rm B}T}\right) + (1-y) \exp\left(-\frac{\Delta_2}{k_{\rm B}T}\right) \right]$$
(1)

with the parameters $\gamma_0' = 0.008 \text{ J/mol K}^2$, $\beta' = 0.023 \text{ J/mol K}^4$, y = 0.95, $\Delta_1/k_BT = 12.6 \text{ K}$, and $\Delta_2/k_BT = 5.0 \text{ K}$ for Sample 1. However, the approximation of Eq. (1) gives a very small contribution of the second band to the electronic specific heat data of Sample 1 ($y \sim 0.95$), which causes the multi-band model not to be clearly defined. The C/T data also can be well approximated by the one-gap scenario, where in Eq. (1) y = 1, then the fitting parameters γ_0' and β' are obtained similar, and $\Delta/k_BT = 11.4 \text{ K}$. Our previous investigations of a number of similar quasiskutterudite superconductors documented their multi-band superconductivity^{19,32}, however, in the case of Sample 1, the specific heat does not give an unambiguous answer, whether the system is a dirty one-gap or two-gap superconductor.

The normal-state electronic specific heat coefficient $\gamma_0^{(n)}$ and the lattice specific heat coefficient β were obtained for Sample 1 at $T > T_c$ by a least-squares fit of the C(T)/T data to $C(T)/T = \gamma_0^{(n)} + \beta T^2$, which provides $\gamma_0^{(n)} = 18 \text{ mJ/mol K}^2$. The similar least-squares fit of the 3 T data gives a Sommerfeld parameter $\gamma_0^{(sc)} = 36.2 \text{ mJ/mol K}^2$ in the superconducting state $(T < T_c)$. The same least-squares analysis gives $\gamma_0^{(n)} = 5.5 \text{ mJ/mol K}^2$ and $\gamma_0^{(sc)} = 47.6 \text{ mJ/mol K}^2$ (B = 3 T), respectively for Sample 2. For a classic BCS superconductors with a Debye lattice, the normal state would appear as a straight line $C/T = \gamma_0^{(n)} + \beta T^2$, and the electronic term would vanish exponentially at low temperatures in the superconducting state, so that below about $\sim T_c/7$ only the lattice specific heat contribution should survive. Therefore the initial slopes of both curves $C^{(n)}/T$ obtained for $T > T_c$ (B = 0) and $C^{(sc)}/T$, measured under magnetic fields $B > B_c$ at $T < T_c(0)$, should be equal.

This is not the case here. The possible γ_0 discrepancies could be addressed to a vortex effect. For a classic isotropic s-wave superconductor (e.g., $Nb_{77}Zr_{23}^{43}$), the specific heat at $T < T_c$ is dominated by that of the vortex cores, the number of which is proportional to the field. As a result, one observes at T \rightarrow 0 a field dependence of $\gamma_0^{(sc)}$. Similar $\gamma_0(H)$ behavior was also reported for other skutterudite-like superconductors $(R_3M_4\text{Sn}_{13}^{44-46}, \text{Lu}_5\text{Rh}_6\text{Sn}_{18}, \text{Y}_5\text{Rh}_6\text{Sn}_{18}^{47,48}, \text{and Sc}_5\text{Rh}_6\text{Sn}_{18}^{49})$. For example, $\gamma_0^{(sc)}(H)$ for Lu₅Rh₆Sn₁₈ and Y₅Rh₆Sn₁₈ is continuously increasing from a few mJ/mol K² in the normal state $(T > T_c \text{ and } H = 0)$, up to the value of about 60 mJ/mol K² under H = 5 T at T = 0.7 K. A linear increase in $\gamma_0^{(sc)}(H)$ was obtained for Lu₅Rh₆Sn₁₈, while for Y₅Rh₆Sn₁₈ $\gamma_0^{(sc)}(H) \sim H^{1/2}$ ⁴⁸. Based on these results, Lu₅Rh₆Sn₁₈ was interpreted as a BCS superconductor with an isotropic gap, while its Y₅Rh₆Sn₁₈ equivalent has anisotropic gap with a node. The field increased $\gamma_0^{(sc)}$ is also a strong evidence in favor of gap anisotropy or different gaps on different sheets of the Fermi surface, like in MgB_2 . This scenario, however, seems to be unlikely for Lu₅Rh₆Sn₁₈ superconductor. In Fig. 11, the specific heat of Sample 1 exhibits a change of slope in C(T) at about 300 K.This phenomenon is most likely related to the process of lattice relaxation and also was observed in a similar T-region for the isostructural $Y_5Rh_6Sn_{18}$ quasiskutterudite system²⁸. Figure Fig. 12 shows the specific heat isotherms $C_T(B)$ as a function of magnetic field B, which for temperatures $T < T_c$ exhibit a clear kink at the critical field H_{c2} and linear behavior under the fields lower than H_{c2} . This behavior is usually attributed to the s-wave one-band superconductivity.

Figure 13 shows the resistivity of Sample 1 and Sample 2. For both samples, the resistivity drop indicates the superconducting transition at T_c^{\star} ($\tilde{T}_c^{\star} \gtrsim T_c$, see Table. III). The lower insets display the resistivity for samples 1 and 2 at various applied fields, while the upper inset shows $\ln \rho$ vs $T^{-1/4}$ dependence for Sample 2. As shown in Fig. 13, the characteristics $\rho(T)$ in the normal *metallic state* are for these two samples quite different, for sample 1 the $\rho(T)$ plot is typical for metals, while the resistivity of the off-stoichiometric Sample 2 indicates its semimetallic nature and exhibits a negative temperature coefficient (TCR) $d\rho/dT < 0$ in a large temperature range $T_c < T < 160$ K. However, this unusual increase in ρ with decreasing T does not exhibit a linear change, as could be expected for strongly disordered alloys⁵⁰, nor it obeys an activated law, while for (60 < T < 160) K $\rho(T)$ obeys Mott's law $\rho \propto \exp[(\frac{\Delta_M}{k_B T})^{1/4}]$, known as Mott variable-range hopping effect⁴⁰ (Δ_M characterizes the pseudogap in the band structure near the Fermi level). In the case of metals, when a conduction and valence band overlap slightly giving a finite DOS at the Fermi energy, a *pseudogap* or minimum in the DOS is expected, as first suggested by $Mott^{41}$. When the overlap increases, the states at ϵ_F are delocalized, and a metalinsulator transition of Anderson type is possible; at the



FIG. 11. (a) Temperature dependence of specific heat, C(T), for Sample 1, measured in the heating-cooling cycles. The inset displays C(T)/T data in various magnetic fields. The dark blue line is the best fit of Eq. (1) to the C(T)/T data in the temperature region $T < T_c$. (b) Temperature dependence of C(T) for Sample 2. The inset displays C(T)/T data in various magnetic fields.

limit of weak localization, conduction by hopping according to $\sigma \propto \exp[(-\frac{\Delta_M}{k_B T})^{1/4}]$ will occur in disordered materials. An agreement with Mott variable-range hopping behavior was observed, e.g., for some *d*-electron semiconducting Heusler alloys (c.f. ZrNiSn and TiNiSn⁵¹⁻⁵³) and $Ce_5RuGe_2^{54}$. The *ab initio* calculations predict for stoichiometric $Lu_5Rh_6Sn_{18}$ a pseudogap with a minimum in DOSs at ~ -0.3 eV due to interband hybridization effect (cf. Fig. 7). Previously, for similar R_3 Co₄Sn₁₃ quasiskutterudites $(R = La^{38} \text{ or } Ce^{37})$ we documented, that even a small number of vacancies can shift the pseudogap calculated at similar binding energies of ~ -0.3 eV towards the Fermi level, simultaneously, the presence of defects may reduce this pseudogap after its shift to ϵ_F (this is characteristic of SC Kondo insulators; see, e.g., 55). We expect a similar band structure effect for the off-stoichiometry Sample 2, which as a consequence of vacancies exhibits abnormal semimetallic $\rho(T)$ behavior with accompanying Mott variable-range hopping ef-



FIG. 12. Heat capacity C as a function of magnetic field B at constant temperatures T for Sample 2. Similar behavior was observed for Sample 1).



FIG. 13. Electrical resistivity $\rho(T)$ for Sample 1 and Sample 2. The lower insets show $\rho(T)$ at various externally applied fields for sample 1 and 2, respectively. Inset (c) displays the resistivity data for Sample 2 in coordinates $\ln \rho = f(T^{-1/4})$. Blue line approximates the linear $\ln \rho$ vs $T^{-1/4}$ behavior in the temperature range between 60 K and 160 K.

fect in its metallic state. The TDOS calculations done for ${\rm Lu}_{5-\delta}{\rm Rh}_6{\rm Sn}_{18}$ with Lu deficiency (simulated by va-

cancies located at Lu sites), should better approximate the band structure of the experimental compositions and provide more information about the shift of the pseudogap in DOS towards the Fermi level. We therefore carried out similar DFT calculations for Lu_{4.5}Rh₆Sn₁₈ with the stoichiometry more close to that obtained from microanalysis. The *ab initio* calculations documented the shift of pseudogap in TDOS of Lu_{4.5}Rh₆Sn₁₈ by 0.1 eV towards ϵ_F in comparison to the stoichiometric variant 5-6-18, as shown in Fig. 14, while the energies of the SO Lu $4f^{7/2}$ and $4f^{5/2}$ states were not changed. The calculations did not take into account the Sn vacancies, which could significantly contribute to a greater energy shift of the pseudogap in TDOS towards ϵ_F (cf.³⁸). Within such



FIG. 14. The comparison of TDOS for $Lu_5Rh_6Sn_{18}$ and $Lu_{4.6}Rh_6Sn_{18}$ near the Fermi level.

a scenario the resistivities shown in Fig. 13 well correlate with the specific heat data in Fig. 11. Namely, Sample 1 with a hybridization pseudogap in DOS at -0.3 eV has a good metallicity, characterized by small normal state residual resistivity $\rho_n(0) \sim 5 \ \mu\Omega \text{cm}$, while $\rho_n(0)$ of the off-stoichiometric Sample 2 is about two orders of magnitude larger due to a possible shift of the pseudogap towards ϵ_F . Simultaneously, the electronic specific heat coefficient $\gamma_0^{(n)}$ obtained in the normal state for Sample 1 is 18 mJ/mol K² (\equiv 467 erg/cm³ K²), while a value of $\gamma_0^{(n)} = 5.5 \text{ mJ/mol K}^2 \ (\equiv 142 \text{ erg/cm}^3 \text{ K}^2)$ for semimetallic Sample 2 is much smaller. Such divergent behaviors seen in two different $Lu_{5-\delta}Rh_6Sn_{18}$ samples result from their different real electronic structures near ϵ_F generated by vacancies and accompanying changes in the density of states $2N(\epsilon_F)$ (cf. Table III). It is worth it to note our earlier paper⁵⁶, where we documented different field skutterudite CeOs₄Sb₁₂ single-crystal specimens - all obtained in one technological process by flux method, a spectrum of various conductivities from metallic to semiconducting, as a result of the changed number of vacancies in the Sb sublattices, depending on which

crystal was measured (cf. Fig. 2 in Ref.⁵⁶). Then, one can comment that the temperature dependence of ρ , previously reported by Zhang et al.⁵⁷ for single crystalline Lu₅Rh₆Sn₁₈, which is similar to that obtained for Sample 2. Both the band structure properties of Lu₅Rh₆Sn₁₈ near the Fermi level from *ab initio* calculations, as well as its various electric transport properties depending on the stoichiometry of this compound - support the assumption that the semimetallic behavior and negative TCR effect in $\rho(T)$ reported for single crystals of Lu₅Rh₆Sn₁₈⁵⁷ also result from the off-stoichiometry effect.

The low-T resistivity of Sample 1 exhibits a field induced positive magnetoresistivity (MR) in the normal metallic state, and the isothermal increase in ρ_T vs B is linear, $\rho_T = \rho B$, with coefficient $\rho \simeq 1 \ \mu \Omega cm/T$, as is shown in inset (a), Fig. 13. Similar positive MR effect has been previously documented for a series of metallic (e.g., $Y_3Ir_4Ge_{13}^{58}$) or superconducting (La₃M₄Sn₁₃³⁶) quasiskutterudites, and was attributed to the Coulomb interactions between the *d*-electrons of transition metal M which dominate the field-dependent electronic transport in these materials. In Fig. 7 the DFT band structure calculations confirm the d-band character of the conduction electrons, which dominate the DOS at ϵ_F . The field induced magnetoresistivity effect is, however, not observed for the off-stoichiometry $Lu_{4.6}Ru_6Sn_{18}$. For this semimetallic sample with the pseudogap expected at the Fermi level, the d electrons correlation effect is not possible.



FIG. 15. Electrical resistivity in cooling/heating cycles for the Sample 1 and Sample 2, between 150 K and 400 K.

Figure 15 shows the cooling-heating evolution of $\rho(T)$ data in the temperature range 150 < T < 400 K. A clear kink in ρ at about 290 K and a hysteresis is observed for Sample 2, while Sample 1 shows only a weak change in

the slope of $\rho(T)$ without any hysteresis at this temperature. The phenomenon seen in the electrical resistivity is most likely related to the process of thermal lattice relaxation, and is also evidenced by the specific heat data in Fig. 11.

C. Superconductivity of $Lu_{5-\delta}Rh_6Sn_{18}$ in the presence of atomic disorder; Experimental results and comparison with BCS theory

Now we analyze the experimental data: the coefficient of the electronic heat capacity $\gamma_0^{(n)}$, normal state resistivity $\rho_n(0)$ approximated to T = 0, and the measured critical-field slopes near T_c with predictions of the Ginzburg-Landau-Abricosov-Gorkov (GLAG) theory of type-II superconductivity, to obtain the parameters characteristic of the superconducting and normal-state of the investigated samples [e.g., coherence length $\xi(0)$, penetration depth $\lambda(0)$, GLAC parameter κ , electronic mean free path l(0), and the critical fields $H_c(0)$ and $H_{c1}(0)$]. According to Ref.⁵⁹, all parameters are calculated as a full value, or at the clean ($\xi \ll l$) and dirty limit ($\xi \gg l$), and are listed in Table III. Under the GLAG theory⁶⁰ the slope of $\frac{dH_{c2}}{dT}$ at T_c in the G/K units is

$$-\frac{dH_{c2}}{dT}\Big|_{T=T_c} = \left[9.55 \times 10^{24} \gamma_0^2 T_c \left(n^{2/3} \frac{S}{S_F}\right)^{-2} + 5.26 \times 10^4 \gamma_0 \rho_n\right] [R(\lambda_{tr})]^{-1}, \quad (2)$$

where n is the density of conduction electrons per cm⁻³, S/S_F is the ratio of the real Fermi surface S to the surface $S_F = 4\pi (3\pi^2 n)^{3/2}$ of the free electron gas, and the Gorkov function $R(\lambda_{tr}) \approx 1$ for $\lambda_{tr} \rightarrow 0$ $(\lambda_{tr} \sim \xi(0)/l(0) = 5.51 \times 10^{-21} \rho_n (n^{2/3} S/S_F) (\gamma_0 T_c)^{-1} \approx 0$ for Lu₅Rh₆Sn₁₈). Equation (2) allows one to estimate the value of $n^{2/3} \frac{S}{S_F} = 2.3 \times 10^{13}$ cm⁻² for sample 1 and 0.66 × 10¹³ cm⁻² for sample 2, respectively⁶¹⁻⁶³. Then, the electronic mean free path $l(0) = 1.27 \times 10^4 [\rho_n (n^{2/3} S/S_F)]^{-1} = 1130$ nm is estimated much larger for sample 1 in comparison to l(0) = 85 nm obtained for sample 2, while the Ginzburg-Landau coherence length (full value)

$$\xi_{GL}^{fv} = \left[2.90 \times 10^{32} (T_c \gamma_0)^2 \left(n^{2/3} \frac{S}{S_F} \right)^{-2} + 1.60 \times 10^{12} \rho_n \gamma_0 T_c \right]^{-1/2} [R(\lambda_{tr})]^{1/2} (1-t)^{-1/2}$$
(3)

is ~ 7 nm for both samples. From the Ginzburg-Landau relation $\mu_0 H_{c2}(0) = \Phi_0/2\pi\xi_{GL}^2(0) \xi_{GL}(0) = 8$ nm, where $\Phi_0 = h/2e = 2.068 \times 10^{-15}$ T m² is the flux quantum. The relation $\xi_{GL}^{fv} \ll l(0)$ predicts a clean limit in superconductivity of Lu₅Rh₆Sn₁₈ (sample 1 and 2), although the atomic disorder is evident in both samples. The BCS coherence length $\xi_0^{BCS} =$ $7.95 \times 10^{-17} (n^{2/3}S/S_F)(\gamma_0 T_c)^{-1} \approx 10$ nm is very similar to the value of ξ_{GL}^{fv} . The Ginzburg-Landau penetration depth

$$\lambda_{GL}^{fv} = \left[8.77 \times 10^{15} \gamma_0 \left(n^{2/3} \frac{S}{S_F} \right)^{-2} + 4.83 \times 10^{-5} \rho_n T_c^{-1} \right]^{1/2} [R(\lambda_{tr})]^{-1/2} \times (1-t)^{-1/2}$$
(4)

(see Table III) gives GLAC parameter

$$\kappa_{GL}^{fv} \equiv \lambda_{GL}(0) / \xi_{GL}(0) = \left[1.60 \times 10^{24} T_c \gamma_0^{3/2} \left(n^{2/3} \frac{S}{S_F} \right)^{-2} + 8.78 \times 10^3 \gamma_0^{1/2} \rho_n \right] [R(\lambda_{tr})]^{-1} \gg 1, \quad (5)$$

which determines $Lu_{5-\delta}Rh_6Sn_{18}$ (Sample 1 and 2) to be a superconductors of type II. Our analysis also includes the dirty limit, where the GLAG parameter $\kappa^d_{GL} =$ $7.49 \times 10^3 \gamma_0^{1/2} \rho_n^{59}$ is 0.8 or 13 for samples 1 and 2, respectively, i.e., a much smaller value of κ_{GL}^d than expected for a superconductor of type II. However, $\kappa^d_{GL} \sim 0.8$ for Sample 1 is close to $1/\sqrt{2}$, that separates the superconductivity of the type I ($\kappa < 1/\sqrt{2}$) and type II ($\kappa > 1/\sqrt{2}$). Then, the critical field $H_c^d(0) = \frac{H_{c2}}{\sqrt{2}\kappa_{GL}^d} = 4.7$ T would be estimated for sample 1 almost equal to its critical field $H_{c2} = 5.2$ T, which drastically deviates from the experiment (cf. Table III). In the clean limit this expression, however, gives $H_c^c(0) \approx 0.03$ T (300 G), in accordance with an alternate estimate of $H_c(0) = 0.0373 \text{ T} (373 \text{ G})$, base on the expression $H_c(0) = 4.23T_c\sqrt{\gamma_0}$ (as shown by Table III). For sample 2 $\kappa_{GL} \gg 1/\sqrt{2}$ for both: the clean and dirty limits and $H_c(0)$ is calculated 0.02 T (clean limit) or 0.23 T (dirty limit), respectively. It can therefore be suggested that the $Lu_{5-\delta}Rh_6Sn_{18}$ samples are largely homogeneous, however, with possible intersite and/or displacive³² atomic disorder present in both samples (1 and 2), or even with fluctuations in composition as it was documented for sample 1. It is worth it to note, that only in the moderate disorder regime, the characteristic relation $\xi_{GL}^d(0) = \sqrt{\xi_0^{BCS} l(0)}$ is roughly satisfied for both samples.

The observed relation $\xi_0 \ll l(0)$ also justifies that $H_{c2}(T)$ can not be well approximated with the Werthamer-Helfand-Hohenberg (WHH)^{60,64} or Maki-de Gennes⁶⁵ theories for a dirty superconductor (cf. Fig. 16). The microanalysis, however, confirms the presence of moderate atomic disorder in both samples, and shows a periodic fluctuation in composition on a long distance of about 25 μ m for sample 1 ⁶⁶. (*i*) From the local atomic disorder results the presence of the *high temperature phase* T_c^* , the effect $T_c^* - T_c \approx 5 \times 10^{-2}$ K is weak but experimentally confirmed for sample 1 and 2. (*ii*) Simultaneously, the enhanced T_c of Sample 1 by about 0.4 K with respect to T_c of Sample 2 can be due to the periodic inhomogeneity effect. Very similar enhancing of the superconductivity by fluctuation of the composition was recently documented and discussed for $Y_5 Rh_6 Sn_{18}^{19}$ within the Gastiasoro and Andersen theoretical model¹⁸.

The BCS theory gives a relation between T_c , $\langle \omega \rangle$, and the interaction strength $N(\epsilon_{\rm F})U$

$$T_c = 1.14 \langle \omega \rangle \exp[-1/(N(\epsilon_{\rm F})U)]. \tag{6}$$

The equivalent of $N(\epsilon_{\rm F})U$ is approximately⁶⁷

$$N(\epsilon_{\rm F})U \to \frac{\lambda - \mu^{\star}}{1 + \lambda},$$
 (7)

where μ^* is the Coulomb pseudopotential of Morel and Anderson⁶⁸,

$$\mu^* = \frac{N(\epsilon_{\rm F})U}{1 + N(\epsilon_{\rm F})U\ln(E_B/\omega_0)},\tag{8}$$

and electron-phonon coupling parameter^{69,70}

$$\lambda = \frac{N(\epsilon_{\rm F})\langle I^2 \rangle}{M_A \langle \omega^2 \rangle}.\tag{9}$$

In Eqs. (6) - (9) $\langle I^2 \rangle$ represents the square of the electronic matrix element of electron-phonon interactions averaged over the Fermi surface, $\langle \omega \rangle \sim \theta_D/1.2$ is an average phonon frequency, $N(\epsilon_{\rm F})$ is a density of states at the Fermi energy in states per eV and per spin, M_A is the atomic mass, E_B is the electronic bandwidth, and ω_0 is the maximum phonon frequency.

From Eq. (8) and (7), one is able to determine¹⁹

$$N(\epsilon_{\rm F})U = \frac{-[2+\lambda(1-x)] + [\lambda^2(1+x)^2 + 4\lambda + 4]^{1/2}}{2x(1+\lambda)},$$
(10)

where $x = \ln(E_B/\omega_0)$. For Sample 1 $T_c = 4.06$ K, $T_c^{\star} = 4.09$ K, $\theta_D = 149$ K, and $E_B = 5$ eV (cf. Fig. 7), then Eq. (6) allows to estimate $N(\epsilon_{\rm F})U = 0.2815$ for the T_c bulk phase, and $[N(\epsilon_{\rm F})U]^* = 0.2821$ for inhomogeneous T_c^{\star} phase, respectively. From Eq. (10) one can calculate $N(\epsilon_{\rm F})U$ as a function of λ , for the T_c and T_c^{\star} phase, respectively, and then compare them with the appropriate $N(\epsilon_{\rm F})U$ quantities obtained experimentally from Eq. (6). The proposed self-consistent procedure gives the best agreement between calculated and experimentally obtained $N(\epsilon_{\rm F})U$ for $\lambda = 0.53(4)$ in the case of the bulk T_c phase and $\lambda^* = 0.54(0)$ for the disordered T_c^{\star} phase, respectively. The λ and λ^{\star} are, however, very similar, which again suggests that $Lu_5Rh_6Sn_{18}$ is largely homogeneous. Similar self-consistent action gives more similar $\lambda = 0.52(0)$ and $\lambda^* = 0.52(2)$ for Sample 2. The λ parameter obtained self-consistently can be verified; e.g., by the analysis of the normal-state specific heat in a standard way (at $T < T_c$ and under magnetic field B) according to the expansion $C(T \to 0) = \gamma_0 T + C_{ph}$, where in the first term $\gamma_0 = \frac{\pi^2 k_B^2 N_A}{3} 2N(\epsilon_F)(1+\lambda)$ the correction factor $(1 + \lambda)$ remains as a consequence of the different electron-phonon renormalizations of the band

erg	00	1 - 1 or - 1	$n^{2/3} \frac{S}{S_F}$	l(0)	ξ(0)	$\lambda(0)$	$\kappa(0)$	T_c	$T_c^* a$	$H_{c2}/d1$	Π_c	H_{c1}	H_{c2}
, - 5	g/cm ² K ²	$10^{-6}\times\Omega {\rm cm}$	$10^{13} \times \mathrm{cm}^{-2}$	nm	nm	nm		К	К 1	$0^4 \times G/1$	K G	IJ	$10^4 \times G$
Sample 1	467	4.9	2.3	1130	$\xi_0^{BCS}(0) = 9.6$	$\lambda_L(0) = 1240$		4.06	.09	-1.62	373	10	5.2
					$\xi_{GL}^{fv}(0) = 7.06$	$\lambda_{GL}^{fv}(0) = 883$	$\kappa^{fv}_{GL}(0) = 125$						
					$\xi^c_{GL}(0)=7.10$	$\lambda^c_{GL}(0) = 880$	$\kappa^c_{GL}(0) = 124$						
					$\xi^d_{GL}(0) = 88.8$	$\lambda^d_{GL}(0) = 70$	$\kappa^d_{GL}(0) = 0.8$						
Sample 2	142	147	0.66	131	$\xi_0^{BCS}(0) = 10.0$	$\lambda_L(0) = 2401$		3.69 3	.75	-1.73	229	1	5.3
					$\xi^{fv}_{GL}(0)=7.0$	$\lambda_{GL}^{fv}(0) = 1744$	$\kappa^{fv}_{GL}(0) = 245$						
					$\xi^c_{GL}(0) = 7.4$	$\lambda^c_{GL}(0) = 1691$	$\kappa^c_{GL}(0) = 229$						
					$\xi^d_{GL}(0) = 25.0$	$\lambda^d_{GL}(0) = 405$	$\kappa^d_{GL}(0) = 13$						

GLAC co penetratic field $H_c =$

structure density of states at the Fermi level. The second term is the low-temperature expansion of the lattice specific heat. For $2N(\epsilon_F) = 11.5$ states/eV f.u. from DFT calculations and $\lambda = 0.53(4)$, the estimated $\gamma_0 = 41.72$ mJ/mol K² matches well the experimental data ($\gamma_0^{(sc)}$) measured in the superconducting state under magnetic field namely, 47.6 mJ/mol K² for Sample 2, and 36.2 mJ/mol K² for Sample 1. The DOS renormalized by electron-phonon coupling explains partially the enhanced Sommerfeld coefficient, however, for correct interpretation one needs to consider the field effect on $\gamma_0^{(sc)}$ too.



FIG. 16. The upper critical field H_{c2} vs T for $\text{Lu}_{5-\delta}\text{Rh}_6\text{Sn}_8$ (Sample 1 and 2). The points are determined from specific heat $C_B(T)$ and /or $C_T(B)$ (filled squares) and from resistivity $\rho_B(T)$ (filled diamonds) measurements. The brown open squares are the data from Ref. 57 for comparison. The H-Tdata are well approximated by GL equation (red dotted curve for sample 1 and light green dotted line for sample 2). For both samples, 1 and 2, T_c^* (filled squares) is measured slightly larger by ~ 0.02 K than T_c (filled diamonds) for B = 0. The solid red and dark green curves are obtained by the single band WHH model using Eq. (11).

The dotted curves in Fig. 16 represent the best fit of the $H_{c2}(T)$ data by the GinzburgáÅŞLandau (GL) formula: $H_{c2}(T) = H_{c2}(0) \frac{1-t^2}{1+t^2}$, where $H_{c2}(0)$ is the upper critical field at T = 0. The H - T data for samples 1 and 2 are well described by the GL equation with similar $H_{c2}(0) \approx 5.3$ T. For comparison, Fig. 16 also displays the respective temperature dependencies of H_{c2} derived within the WHH model, which includes orbital and Zeeman pair breaking^{60,64}. For a single band superconductor in a dirty limit, the model yields the well-known WHH formula for the upper critical field:

$$H_{c2}(0) = -0.69T_c \left. \frac{dH_{c2}}{dT} \right|_{T=T_c}.$$
 (11)

For our samples the slope $\mu_0 \frac{dH_{c2}(T)}{dT} = -1.63 \text{ T/K}$ (sample 1) or -1.69 T/K for sample 2. Within the WHH theory $H_{c2}(0) \cong 4.93$ T is for both samples ~ 0.4 T smaller than that, obtained experimentally and approximated by the GL expression. Different mechanisms have been proposed to explain this behavior, such as strong coupling effects, multi-band electronic structure, and/or disorder^{32,71}. In the case of the $Lu_{5-\delta}Rh_6Sn_{18}$ samples, the multiband model seems to be probable, considering the more complicated band structure of these compounds with the presence of various electronic states at the Fermi level, as shown in Fig. 7. To confirm this hypothesis, the $H_{c2}(T)$ was calculated according to the Gurevich⁷² theory, which adopts the Eilenberger and Usadel equations for a two-band dirty superconductor. Within the model, the reduced magnetic field $h = H_{c2}D_1/2\Phi_0T$ is a solution of the nonlinear equation

$$a_0 \left[\ln t + U(h) \right] \left[\ln t + U(\eta h) \right] + a_2 \left[\ln t + U(\eta h) \right] + a_1 \left[\ln t + U(h) \right] = 0, \quad (12)$$

where $U(x) \equiv \psi(x + 1/2) - \psi(1/2), \psi(...)$ is the digamma function and $\eta = D_2/D_1$ is the ratio of the intraband electron diffusivities D_1 and D_2 . The parameters $a_{0,1,2}$ can be expressed by the intra- and interband BCS superconducting coupling constants $\lambda_{11}, \lambda_{22}, \lambda_{12}$ and λ_{21} . However, fitting the solution of Eq. (12) to $H_{c2}(T)$ data for Lu_{5- δ}Rh₆Sn₁₈ gives $\eta \approx 1$. In this case Eq. (12) reduces to

$$\ln t + U(h) = 0, \tag{13}$$

which is the standard Maki-de Gennes equation for $H_{c2}(T)$ in single band dirty superconductors⁶⁵, which indicates that the role of the second band is practically negligible in the superconductivity of the $Lu_{5-\delta}Rh_6Sn_{18}$ samples.

IV. CONCLUDING REMARKS

The main goal of our comprehensive research of various quasiskutterudites was to document experimentally and interpret the impact of an atomic disorder characteristic of these materials on enhancement of their superconductivity. Since varying amounts of disorder may be present in these materials, and because the superconducting state is effected by various structural defects, vacancies and/or by doping, it is important to precisely identify them, and to understand the role of widely understood defects on the superconductivity. There are several experimental approaches to study the disorder-induced superconductivity in the skutterudite-related cubic $R_3M_4Sn_{13}$ type^{15,73} or tetragonal $R_5 M_6 \text{Sn}_{18}$ -type compounds^{19,32}, where R = Ca and La, or Y and Lu, respectively (see also Ref. 74). One of them is to measure the change of the superconducting transition temperature T_c with well controlled disorder of the sample, which also can be artificially introduced by doping. Recently, we documented the structural defects, like disorder caused by

static displacements of atoms in cages, local disorder due to anti-site positions of the neighboring atoms, or disorder resulting from doping; all these defects contribute to the increase in T_c , observed as T_c^{\star} . The coexisting bulk T_c phase and the high-temperature T_c^{\star} phase and the $T_c^{\star} > T_c$ behavior fit well the mechanism of disordergenerated T_c enhancement, very recently proposed by Gastiasoro and Andersen¹⁸. In accordance with this theoretical model, the structural defects at a low concentration level can be understood as the elemental impurity effect, giving the basis for interpretation of the increase in T_c at the level of the dilute disorder case. However, the effect of stronger fluctuations in both atomic disorder and composition in $Y_{5-x}Ca_{x}Rh_{6}Sn_{18}$ ($x > 2, {}^{19}$) leads to a significant increase in T_c as a result of stoichiometry fluctuations, and it is well interpreted by the Gastiasoro and Andersen model of dense disorder in a conventional one-band superconducting system. Similar enhancing of superconductivity by the increase in atomic disorder is also observed for the $Lu_{5-\delta}Rh_6Sn_{18}$ compounds, which confirms that this anomalous behavior is characteristic of the family of skutterudite-related compounds. The microanalysis documented that Sample 2 is a homogeneous system with small nanoscale atomic disorder, characterized by the transition to the superconducting state at $T_c = 3.7$ K, while Sample 1 exhibits both nanoscale inhomogeneity and long-range fluctuations in composition, and its $T_c^{\star} \sim 4.1$ K. If one treats Sample 2 as a reference compound for Sample 1, then the $T_c^{\star} > T_c$ relation can be interpreted under the Gastiasoro and Andersen model as the effect of increased disorder in Sample 1.

Our systematic research on the series of quasiskutterudites allowed to propose a phenomenological model that explains the $T_c^{\star} > T_c$ behavior, based on the documented experimentally larger lattice stiffening in the T_c^{\star} phase with respect to the bulk effect below T_c . For various quasiskutterudites investigated under pressure we always found $\left|\frac{dT_c^{\star}}{dP}\right| > \left|\frac{dT_c}{dP}\right|$, and accompanying $T_c^{\star} > T_c$ behavior, both relations are characteristic of these materials^{74,75}. Considering, that the *P* dependence on θ_D is given by the Grüneisen parameter $\gamma_G = -\frac{d \ln \theta_D}{d \ln V}$ and determines the lattice stiffening, we documented experimentally $\gamma_G^* > \gamma_G$ for T_c^* and T_c phases, respectively (e.g., for Y₅Rh₆Sn₁₈ doped with Ca¹⁹ and for La₃Rh₄Sn₁₃⁷⁴). The relationship between γ_G and T_c seems to be correct for all disordered skutterudite-related superconductors as well as for the filled skutterudite PrOs₄Sb₁₂ superconductor⁷⁶. This is one of the most interesting results obtained for this intriguing single crystal of PrOs₄Sb₁₂, namely the observation of two various superconducting transitions at T_c and T_c^* , and the measured value of $\left| \frac{dT_c}{dP} \right|$, which is ~ 20% larger than $\left| \frac{dT_c}{dP} \right|$ ⁷⁶. For the family of quasiskutterudite superconductors our research has confirmed, that the coupling λ parameter correlates with γ_G and always $\lambda^* > \lambda$ ⁷⁴, this is also the case of Lu_{5-\delta}Rh₆Sn₁₈.

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 $\exp\left[-\frac{(\Delta-\Delta_0)^2}{2D}\right]$ approximates the specific heat C(T)

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